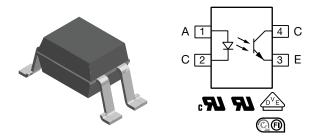
Vishay Semiconductors

Optocoupler, Phototransistor Output, High Reliability, 5300 V_{RMS}



FEATURES

· Excellent CTR linearity depending on forward



Isolation test voltage, 5300 V_{RMS}

- · Fast switching times
- Low CTR degradation
- · Low coupling capacitance
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

LINKS TO ADDITIONAL RESOURCES









DESCRIPTION

The SFH615A-3X018T and SFH615A-4X018T features a variety of transfer ratios, low coupling capacitance and high isolation voltage. This coupler has a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

APPLICATIONS

- Switchmode power supply
- Telecom
- · Battery powered equipment

AGENCY APPROVALS

- UL 1577
- cUL
- DIN EN 60747-5-5 (VDE0884-5) available with option 1
- BSI
- FIMKO

ORDERING INFORMATION						
S F H 6 1 5 PART NUMBER	A - # X 0 1 8 CTR PACKAGE OPTION	TAPE AND REEL 9.27 mm				
AGENCY CERTIFIED / PACKAGE	CTR (%)					
AGENOT GENTILED / PAGRAGE						
UL, cUL, BSI, FIMKO	100 to 200	160 to 320				
SMD-4, option 8	SFH615A-3X008T SFH615A-4X008T					
UL, cUL, BSI, FIMKO, VDE (option 1)	100 to 200	160 to 320				
SMD-4, option 8	SFH615A-3X018T ⁽¹⁾	SFH615A-4X018T				

(1) Also available in tubes: do not add "T" to end

Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		V_R	6	V			
DC forward current		l _F	60	mA			
Surge forward current	t _p ≤ 10 μs	I _{FSM}	2.5	Α			
OUTPUT							
Collector emitter voltage		V _{CEO}	70	V			
Emitter collector voltage		V _{ECO}	7	V			
Collector current		I _C	50	mA			
Collector current	t _p ≤ 1 ms	I _C	100	mA			
COUPLER							
Storage temperature range		T _{stg}	-55 to +150	°C			
Ambient temperature range		T _{amb}	-55 to +100	°C			
Soldering temperature (1)	max. 10 s	T _{sld}	260	°C			

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD)

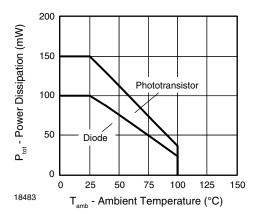


Fig. 1 - Permissible Power Dissipation vs. Ambient Temperature

Vishay Semiconductors

THERMAL CHARACTERISTICS			
PARAMETER	SYMBOL	VALUE	UNIT
LED power dissipation	P _{diss}	100	mW
Output power dissipation	P _{diss}	150	mW
Maximum LED junction temperature	T _{jmax.}	125	°C
Maximum output die junction temperature	T _{jmax.}	125	°C
Thermal resistance, junction emitter to board	θ_{EB}	173	°C/W
Thermal resistance, junction emitter to case	$\theta_{\sf EC}$	149	°C/W
Thermal resistance, junction detector to board	θ_{DB}	111	°C/W
Thermal resistance, junction detector to case	θ_{DC}	127	°C/W
Thermal resistance, junction emitter to junction detector	θ_{ED}	95	°C/W
Thermal resistance, board to ambient (1)	θ_{BA}	195	°C/W
Thermal resistance, case to ambient (1)	θ_{CA}	3573	°C/W

Notes

The thermal model is represented in the thermal network below. Each resistance value given in this model can be used to calculate the
temperatures at each node for a given operating condition. The thermal resistance from board to ambient will be dependent on the type of
PCB, layout and thickness of copper traces. For a detailed explanation of the thermal model, please reference Vishay's thermal
characteristics of optocouplers application note.

(1) For 2 layer FR4 board (4" x 3" x 0.062")

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT	•					
Forward voltage	I _F = 60 mA	V _F	-	1.25	1.65	V
Reverse current	V _R = 6 V	I _R	-	0.01	10	μΑ
Capacitance	V _R = 0 V, f = 1 MHz	Co	-	13	-	pF
OUTPUT						
Collector emitter capacitance	V _{CE} = 5 V, f = 1 MHz	C _{CE}	-	5.2	-	pF
Collector emitter leakage current	V _{CE} = 10 V	I _{CEO}	-	5	100	nA
COUPLER						
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 2.5 \text{ mA}$	V _{CEsat}	-	0.25	0.4	V
Coupling capacitance		C _C	-	0.4	-	pF

Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	SYMBOL	BIN	MIN.	TYP.	MAX.	UNIT
	L = 10 m/s V/ = 5 V/	CTR	3	100	-	200	%
	$I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V}$	CTR	4	160	-	320	%
I _C /I _F	I _E = 1 mA, V _{CE} = 5 V	CTR	3	34	70	-	%
	$I_F = I IIIA, V_{CE} = 5 V$	CTR	4	56	90	-	%

Vishay Semiconductors

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED	NON-SATURATED					
Rise time	I_F = 10 mA, V_{CC} = 5 V, T_A = 25 °C, R_L = 75 Ω	t _r	-	2	-	μs
Fall time	I_F = 10 mA, V_{CC} = 5 V, T_A = 25 °C, R_L = 75 Ω	t _f	-	2	-	μs
Turn-on time	I_F = 10 mA, V_{CC} = 5 V, T_A = 25 °C, R_L = 75 Ω	t _{on}	-	3	-	μs
Turn-off time	I_F = 10 mA, V_{CC} = 5 V, T_A = 25 °C, R_L = 75 Ω	t _{off}	-	2.3	-	μs
Cut-off frequency	I_F = 10 mA, V_{CC} = 5 V, T_A = 25 °C, R_L = 75 Ω	f _{ctr}	-	250	-	kHz
SATURATED						
Rise time	V_{CC} = 5 V, T_A = 25 °C, R_L = 1 k Ω , I_F = 10 mA	t _r	-	3	-	μs
Fall time	$V_{CC} = 5 \text{ V}, T_A = 25 \text{ °C}, R_L = 1 \text{ k}\Omega, I_F = 10 \text{ mA}$	t _f	-	14	-	μs
Turn-on time	V_{CC} = 5 V, T_A = 25 °C, R_L = 1 k Ω , I_F = 10 mA	t _{on}	-	4.2	-	μs
Turn-off time	$V_{CC} = 5 \text{ V}, T_A = 25 \text{ °C}, R_L = 1 \text{ k}\Omega, I_F = 10 \text{ mA}$	t _{off}	-	23	-	μs

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55 / 100 / 21	
Pollution degree	According to DIN VDE 0109		2	
Comparative tracking index	Insulation group Illa	CTI	175	
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V _{ISO}	4420	V _{RMS}
Tested withstanding isolation voltage	According to UL1577, t = 1 s	V _{ISO}	5300	V _{RMS}
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V _{IOTM}	10 000	V _{peak}
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V _{IORM}	890	V _{peak}
Isolation resistance	$T_{amb} = 25 ^{\circ}\text{C}, V_{IO} = 500 \text{V}$	R _{IO}	≥ 10 ¹²	Ω
Isolation resistance	T _{amb} = 100 °C, V _{IO} = 500 V	R _{IO}	≥ 10 ¹¹	Ω
Output safety power		P _{SO}	400	mW
Input safety current		I _{SI}	275	mA
Input safety temperature		T _S	175	°C
Creepage distance			≥8	mm
Clearance distance			≥8	mm
Insulation thickness		DTI	≥ 0.4	mm

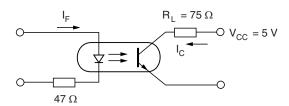
Note

• As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

30

Vishay Semiconductors

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)



isfh615a_01

Fig. 2 - Linear Operation (without Saturation)

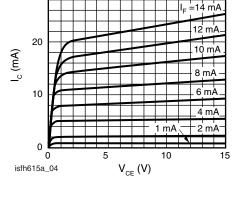
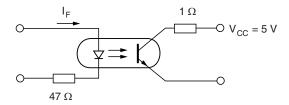


Fig. 5 - Output Characteristics (Typ.) Collector Current vs. Collector Emitter Voltage



isfh615a_02

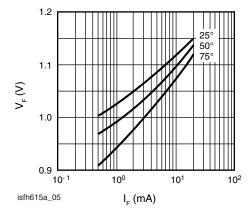


Fig. 6 - Diode Forward Voltage (Typ.) vs. Forward Current



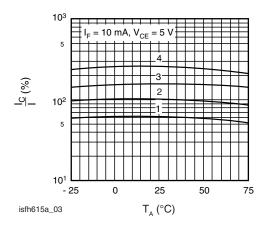


Fig. 4 - Current Transfer Ratio (Typ.) vs. Temperature

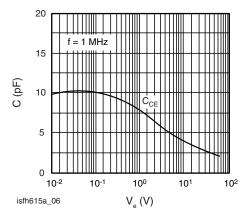


Fig. 7 - Transistor Capacitance (Typ.) vs. Collector Emitter Voltage

Vishay Semiconductors

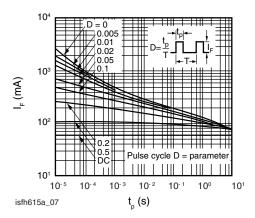
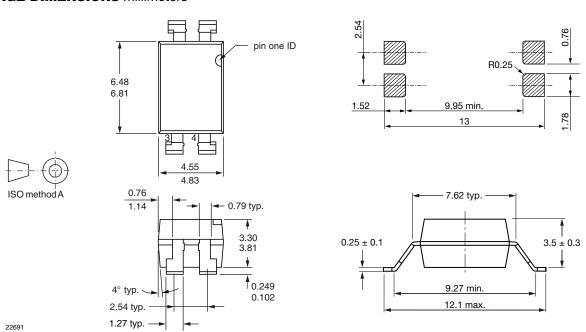


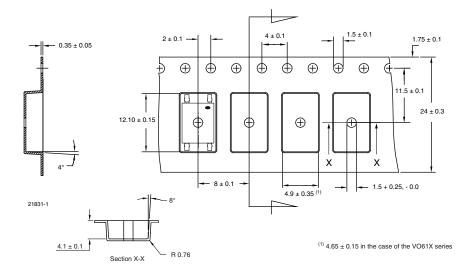
Fig. 8 - Permissible Pulse Handling Capability Forward Current vs. Pulse Width

PACKAGE DIMENSIONS millimeters



Vishay Semiconductors

SMD-4, Option 8



PACKAGE MARKING (example of SFH615A-3X018T)



Notes

- XXXX = LMC (lot marking code)
- VDE logo is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking

TAPE AND REEL PACKING				
TYPE	UNITS/REEL			
SMD-4	1000			

SOLDER PROFILES

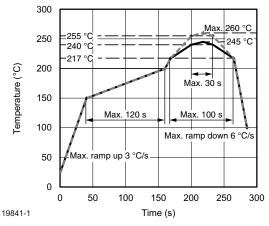


Fig. 9 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions: T_{amb} < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020

ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.